



# CSD16340Q3 25-V N-Channel NexFET™ Power MOSFET

## 1 Features

- Optimized for 5 V Gate Drive
- Resistance Rated at  $V_{GS} = 2.5$  V
- Ultra-Low  $Q_g$  and  $Q_{gd}$
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 3.3-mm x 3.3-mm Plastic Package

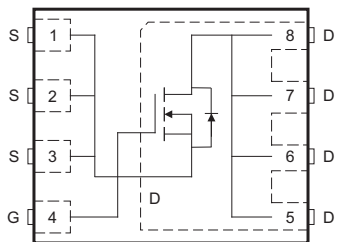
## 2 Applications

- Point of Load Synchronous Buck Converter for Applications in Networking, Telecom, and Computing Systems
- Optimized for Control or Synchronous FET Applications

## 3 Description

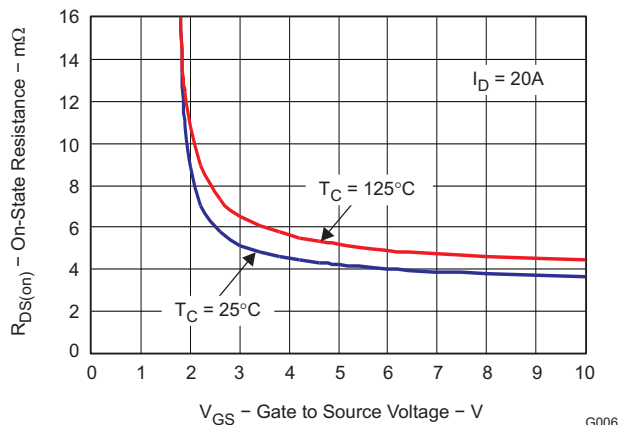
This 25 V, 3.8 mΩ, 3.3 x 3.3 mm SON NexFET™ power MOSFET is designed to minimize losses in power conversion and optimized for 5 V gate drive applications.

**Top View**



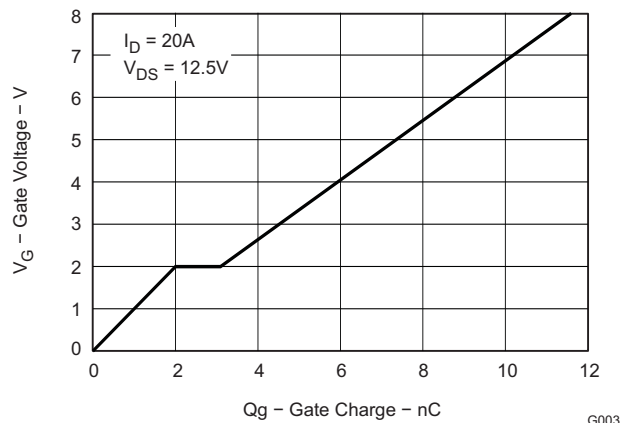
P0095-01

**$R_{DS(on)}$  vs  $V_{GS}$**



G006

**Gate Charge**



G003

## Product Summary

$T_A = 25^\circ\text{C}$		VALUE		UNIT
$V_{DS}$	Drain-to-Source Voltage	25		V
$Q_g$	Gate Charge Total (4.5 V)	6.5		nC
$Q_{gd}$	Gate Charge Gate-to-Drain	1.2		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = 2.5$ V	6.1	mΩ
		$V_{GS} = 4.5$ V	4.3	mΩ
		$V_{GS} = 8$ V	3.8	mΩ
$V_{th}$	Threshold Voltage	0.85		V

## Ordering Information<sup>(1)</sup>

Device	Media	Qty	Package	Ship
CSD16340Q3	13-Inch Reel	2500	SON 3.3 x 3.3 mm Plastic Package	Tape and Reel
CSD16340Q3T	7-Inch Reel	250		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	25	V
$V_{GS}$	Gate-to-Source Voltage	+10 / -8	V
$I_D$	Continuous Drain Current, $T_C = 25^\circ\text{C}$	60	A
	Continuous Drain Current <sup>(1)</sup>	21	A
$I_{DM}$	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ <sup>(2)</sup>	115	A
$P_D$	Power Dissipation <sup>(1)</sup>	3	W
$T_J$ , $T_{stg}$	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$E_{AS}$	Avalanche Energy, single pulse $I_D = 40$ A, $L = 0.1$ mH, $R_G = 25$ Ω	80	mJ

(1) Typical  $R_{\theta JA} = 39^\circ\text{C/W}$  on 1in<sup>2</sup> Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width  $\leq 300$  μs, duty cycle  $\leq 2\%$



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## 4 Revision History

Changes from Revision D (November 2011) to Revision E	Page
• Added 7" reel to Ordering Information .....	<b>1</b>
• Updated Mechanical Information .....	<b>9</b>

Changes from Revision C (June 2011) to Revision D	Page
• Replaced the THERMAL CHARACTERISTICS table with the new Thermal Information Table .....	<b>4</b>
• Replaced <a href="#">Figure 10</a> - Maximum Safe Operating Area .....	<b>6</b>

Changes from Revision B (September 2010) to Revision C	Page
• Deleted the Package Marking Information section .....	<b>9</b>

Changes from Revision A (January 2010) to Revision B	Page
• Changed <a href="#">Figure 2</a> , reversed the order of the $V_{GS}$ labels .....	<b>5</b>

Changes from Original (December 2009) to Revision A	Page
• Changed $Q_g$ in the PRODUCT SUMMARY table from: 6.8 To 6.5 nC .....	<b>1</b>

## 5 Specifications

### 5.1 Electrical Characteristics

(T<sub>A</sub> = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV <sub>DSS</sub>	Drain-to-Source Voltage	V <sub>GS</sub> = 0 V, I <sub>DS</sub> = 250 μA	25			V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 20 V			1	μA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = +10/−8 V			100	nA
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>DS</sub> = 250 μA	0.6	0.85	1.1	V
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	V <sub>GS</sub> = 2.5 V, I <sub>DS</sub> = 20 A	6.1		7.8	mΩ
		V <sub>GS</sub> = 4.5 V, I <sub>DS</sub> = 20 A	4.3		5.5	mΩ
		V <sub>GS</sub> = 8 V, I <sub>DS</sub> = 20 A	3.8		4.5	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15 V, I <sub>DS</sub> = 20 A	121			S
DYNAMIC CHARACTERISTICS						
C <sub>ISS</sub>	Input Capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 12.5 V, <i>f</i> = 1 MHz	1050		1350	pF
C <sub>OSS</sub>	Output Capacitance		730		950	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		53		69	pF
R <sub>g</sub>	Series Gate Resistance	V <sub>DS</sub> = 12.5 V, I <sub>D</sub> = 20 A	1.5		3	Ω
Q <sub>g</sub>	Gate Charge Total (4.5 V)		6.5		9.2	nC
Q <sub>gd</sub>	Gate Charge Gate-to-Drain		1.2			nC
Q <sub>gs</sub>	Gate Charge Gate-to-Source		2.1			nC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>		1			nC
Q <sub>OSS</sub>	Output Charge	V <sub>DS</sub> = 13 V, V <sub>GS</sub> = 0 V	15			nC
t <sub>d(on)</sub>	Turn On Delay Time	V <sub>DS</sub> = 12.5 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A R <sub>G</sub> = 2 Ω	4.8			ns
t <sub>r</sub>	Rise Time		16.1			ns
t <sub>d(off)</sub>	Turn Off Delay Time		13.8			ns
t <sub>f</sub>	Fall Time		5.2			ns
DIODE CHARACTERISTICS						
V <sub>SD</sub>	Diode Forward Voltage	I <sub>S</sub> = 20 A, V <sub>GS</sub> = 0 V	0.8		1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> = 13 V, I <sub>F</sub> = 20 A, di/dt = 300 A/μs	14.5			nC
t <sub>rr</sub>	Reverse Recovery Time		20			ns

# CSD16340Q3

SLPS247E – DECEMBER 2009 – REVISED AUGUST 2014

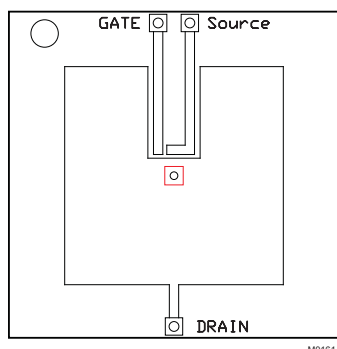
www.ti.com

## 5.2 Thermal Information

THERMAL METRIC <sup>(1)(2)</sup>		CSD16340Q3	UNITS
		Q3 (8 PINS)	
$\theta_{JA}$	Junction-to-Ambient Thermal Resistance	42.0	°C/W
$\theta_{JCTop}$	Junction-to-Case (top) Thermal Resistance	20.6	
$\theta_{JB}$	Junction-to-Board Thermal Resistance	8.8	
$\psi_{JT}$	Junction-to-Top Characterization Parameter	0.3	
$\psi_{JB}$	Junction-to-Board Characterization Parameter	8.7	
$\theta_{JCbott}$	Junction-to-Case (bottom) Thermal Resistance	0.1	

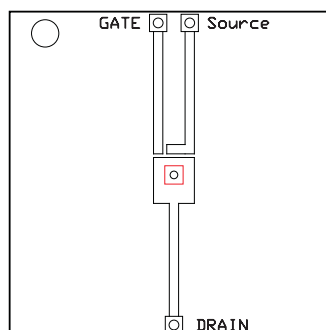
(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

(2) For thermal estimates of this device based on PCB copper area, see the [TI PCB Thermal Calculator](#).



M0161-01

Max  $R_{\theta JA}$  = 58°C/W  
when mounted on  
1 inch<sup>2</sup> of 2 oz. Cu.

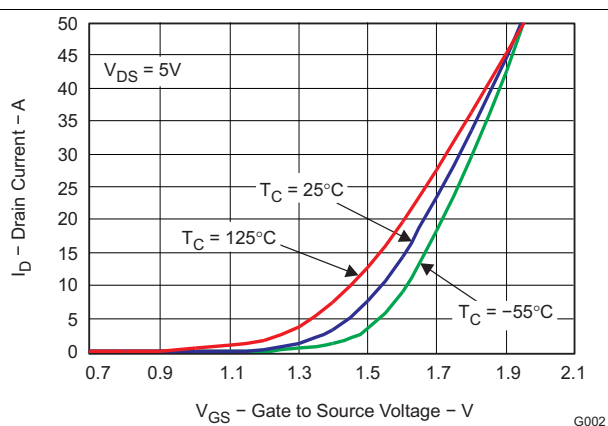
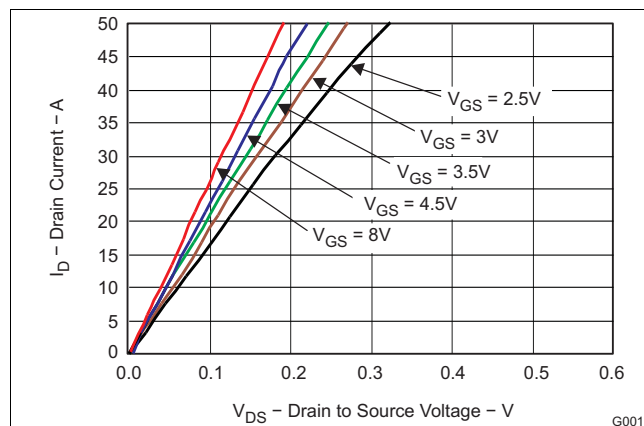
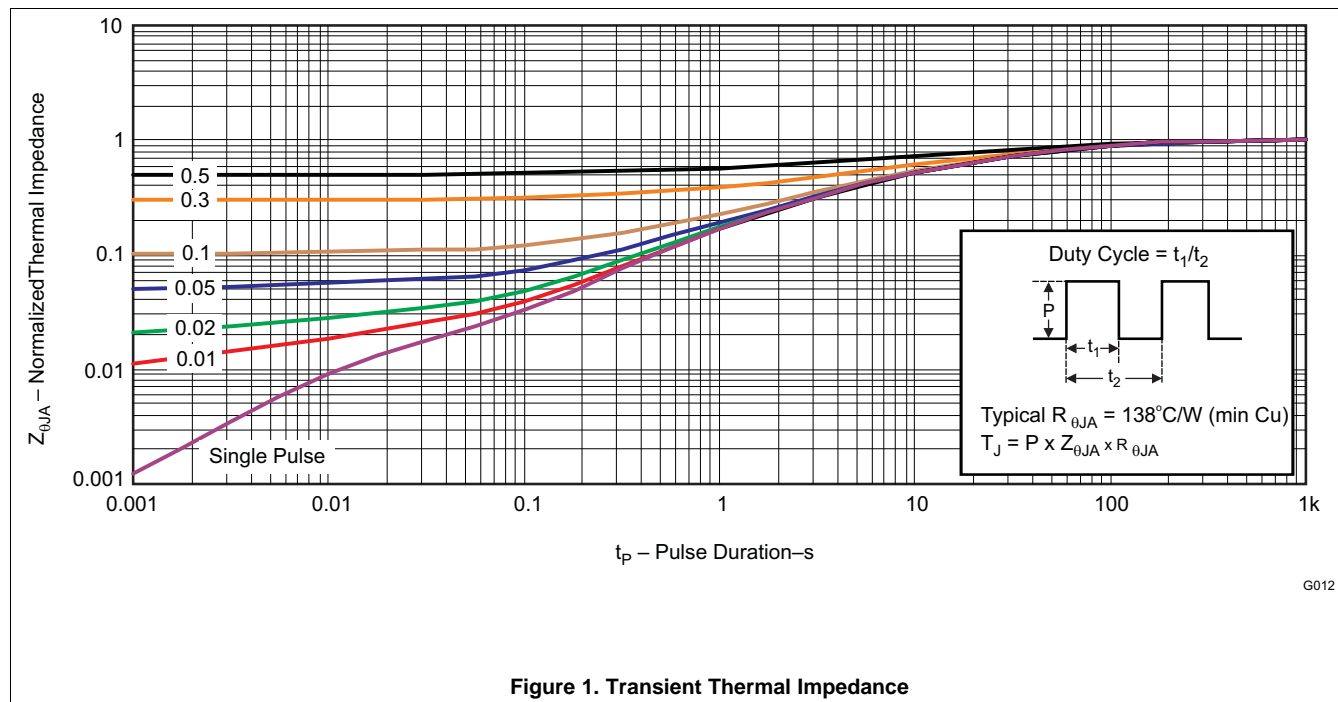


M0161-02

Max  $R_{\theta JA}$  = 162°C/W  
when mounted on  
minimum pad area of  
2 oz. Cu.

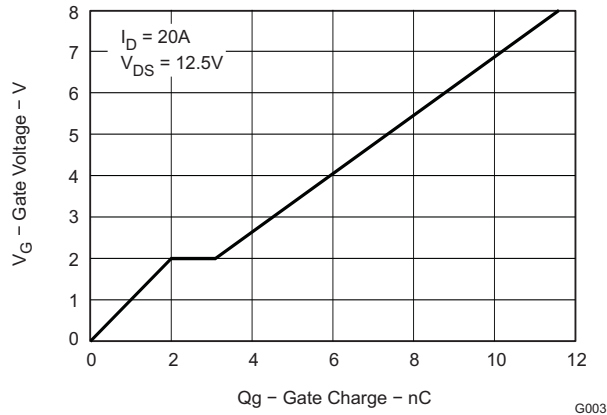
## 5.3 Typical MOSFET Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

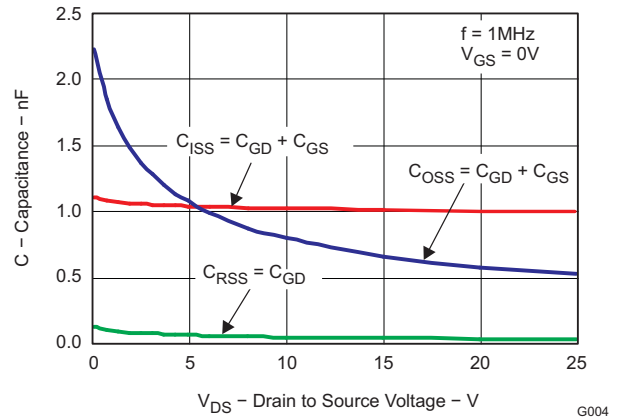


## Typical MOSFET Characteristics (continued)

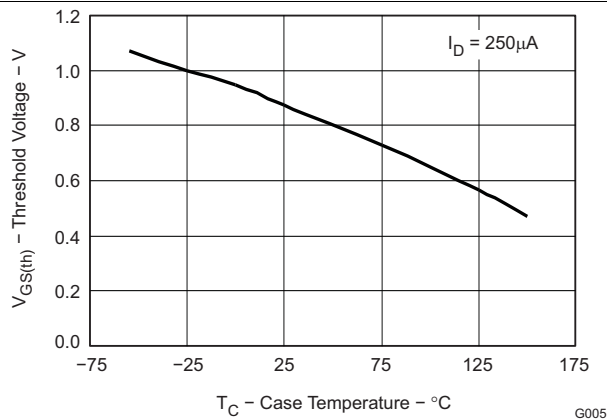
( $T_A = 25^\circ\text{C}$  unless otherwise stated)



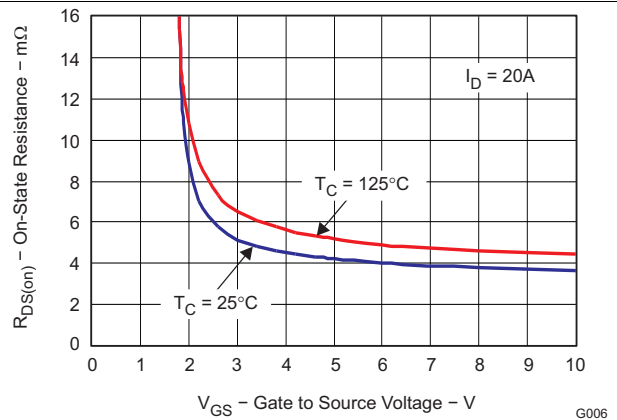
**Figure 4. Gate Charge**



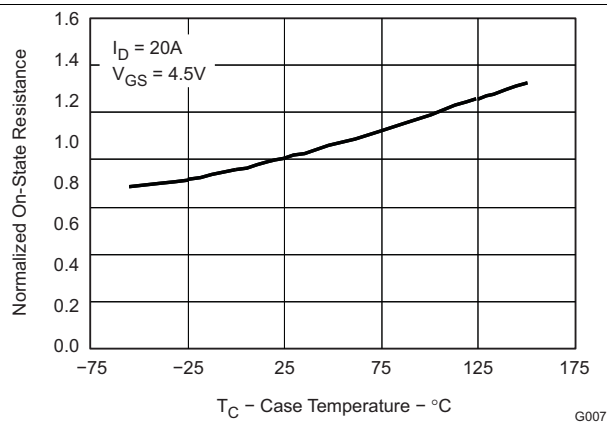
**Figure 5. Capacitance**



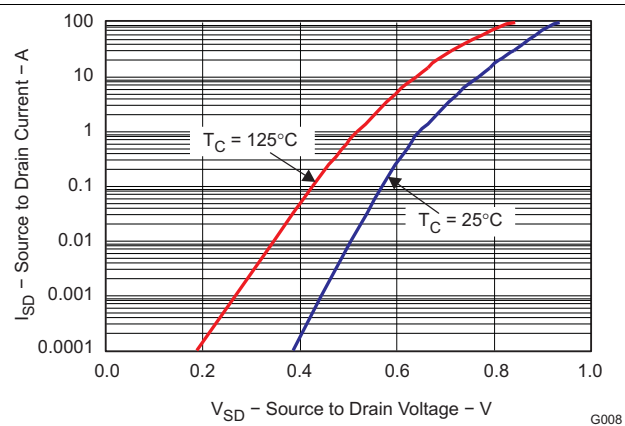
**Figure 6. Threshold Voltage vs Temperature**



**Figure 7. On-Resistance vs Gate Voltage**



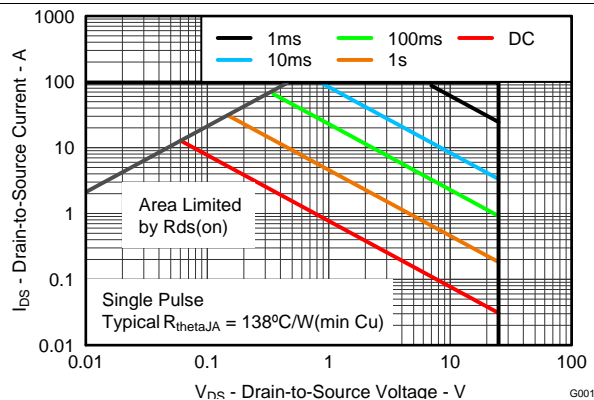
**Figure 8. Normalized On Resistance vs Temperature**



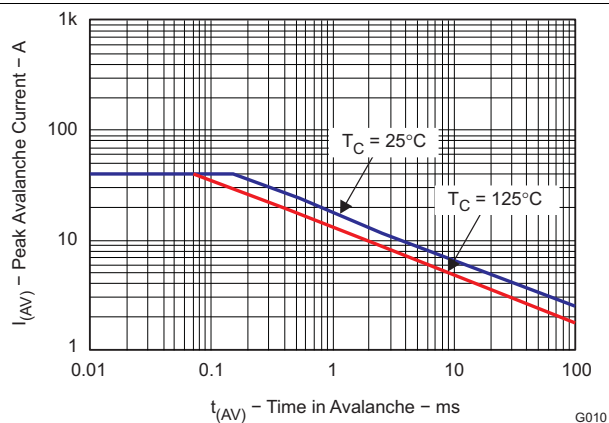
**Figure 9. Typical Diode Forward Voltage**

## Typical MOSFET Characteristics (continued)

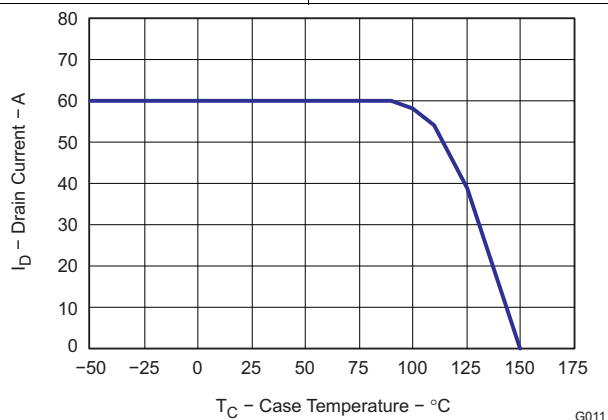
( $T_A = 25^\circ\text{C}$  unless otherwise stated)



**Figure 10. Maximum Safe Operating Area**



**Figure 11. Single Pulse Unclamped Inductive Switching**



**Figure 12. Maximum Drain Current vs Temperature**

## 6 Device and Documentation Support

### 6.1 Trademarks

NexFET is a trademark of Texas Instruments.

### 6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.3 Glossary

[SLYZ022](#) — *TI Glossary*.

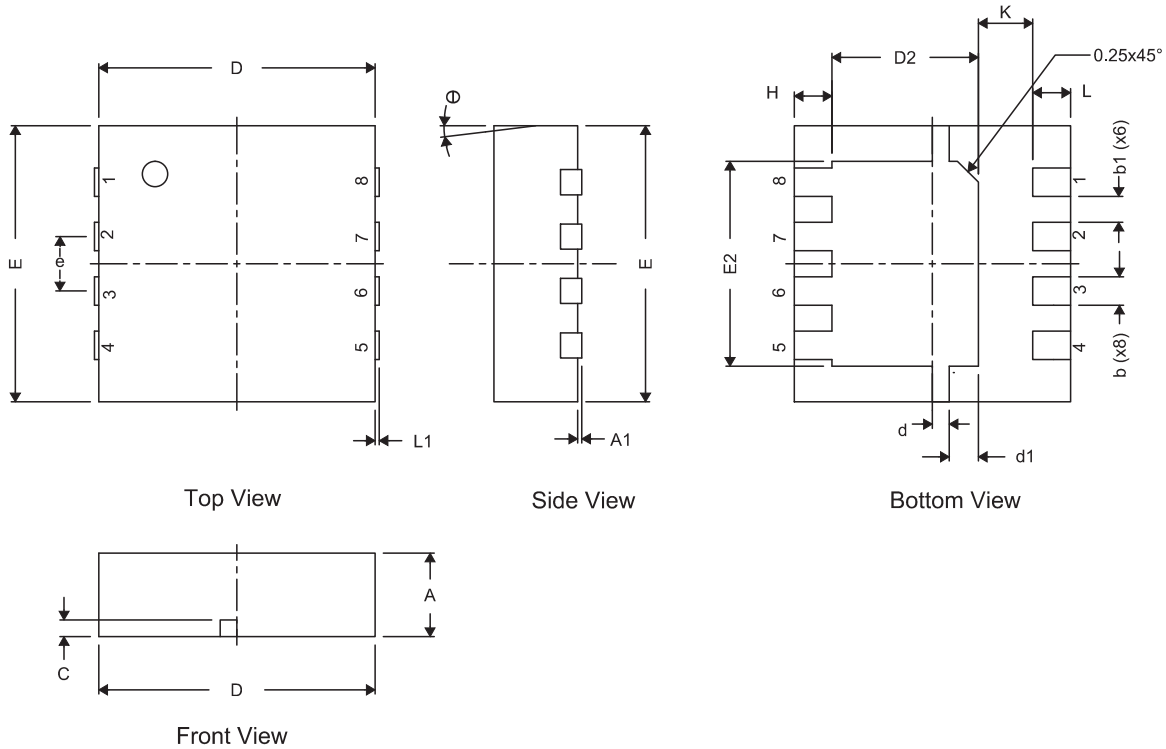
This glossary lists and explains terms, acronyms, and definitions.



## 7 Mechanical, Packaging, and Orderable Information

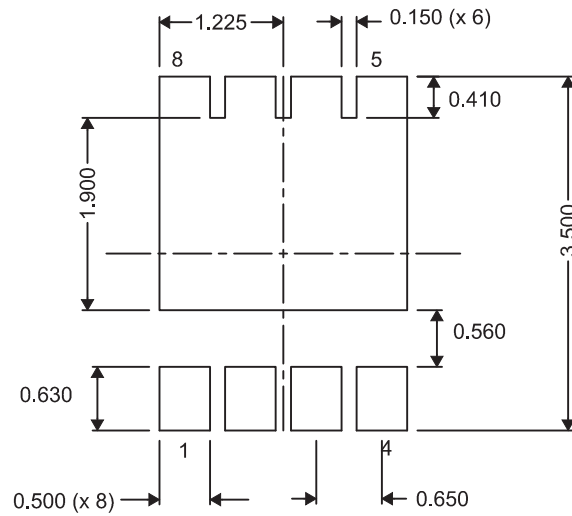
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

### 7.1 Q3 Package Dimensions



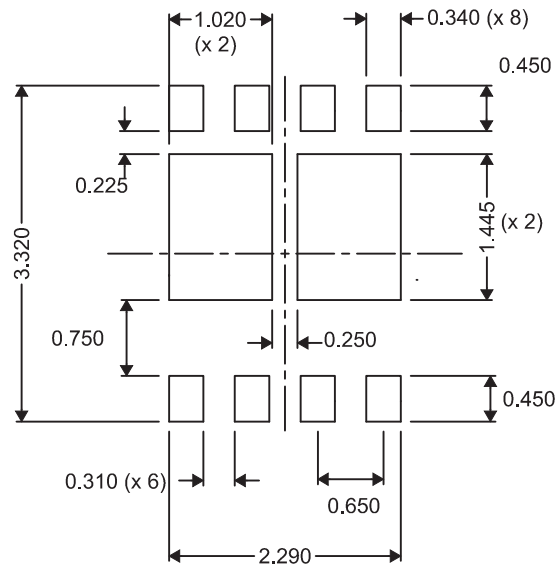
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.950	1.000	1.100	0.037	0.039	0.043
A1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.280	0.340	0.400	0.011	0.013	0.016
b1	0.310 NOM			0.012 NOM		
c	0.150	0.200	0.250	0.006	0.008	0.010
D	3.200	3.300	3.400	0.126	0.130	0.134
D2	1.650	1.750	1.800	0.065	0.069	0.071
d	0.150	0.200	0.250	0.006	0.008	0.010
d1	0.300	0.350	0.400	0.012	0.014	0.016
E	3.200	3.300	3.400	0.126	0.130	0.134
E2	2.350	2.450	2.550	0.093	0.096	0.100
e	0.650 TYP			0.026		
H	0.35	0.450	0.550	0.014	0.018	0.022
K	0.650 TYP			0.026 TYP		
L	0.35	0.450	0.550	0.014	0.018	0.022
L1	0	—	0	0	—	0
θ	0	—	0	0	—	0

## 7.2 Recommended PCB Pattern



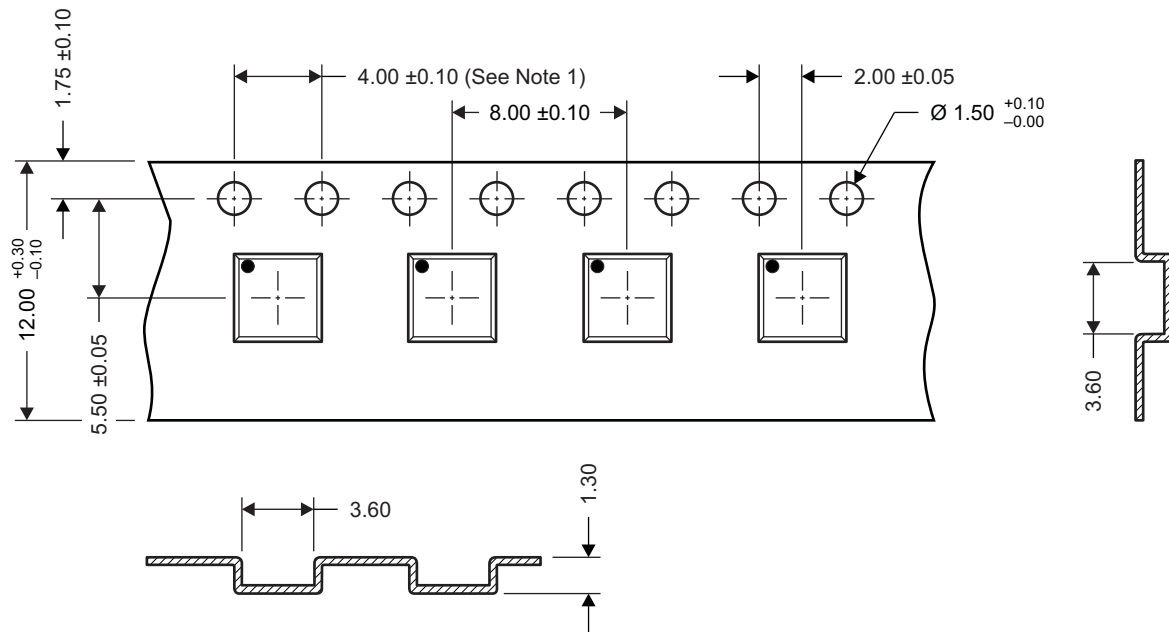
For recommended circuit layout for PCB designs, see application note [SLPA005](#) – *Reducing Ringing Through PCB Layout Techniques*.

## 7.3 Recommended Stencil Opening



All dimensions are in mm, unless otherwise specified.

## 7.4 Q3 Tape and Reel Information



M0144-01

### Notes:

1. 10 sprocket hole pitch cumulative tolerance  $\pm 0.2$
2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
3. Material: black static dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified).
5. Thickness:  $0.30 \pm 0.05$  mm
6. MSL1 260°C (IR and Convection) PbF-Reflow Compatible

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD16340Q3	ACTIVE	VSON-CLIP	DQG	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16340	<a href="#">Samples</a>
CSD16340Q3T	ACTIVE	VSON-CLIP	DQG	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16340	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

### Products

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>
OMAP Applications Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>
Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>

### Applications

Automotive and Transportation	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
Communications and Telecom	<a href="http://www.ti.com/communications">www.ti.com/communications</a>
Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
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### TI E2E Community

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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